## NSN 5962-01-266-1459

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View Online at https://aerobasegroup.com/nsn/5962-01-266-1459 **Body Length:** 0.505 inches **Body Width:** 0.305 inches **Body Height:** 0.100 inches **Maximum Power Dissipation Rating:** 1.0 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and burn in and dynamic and w/enable and w/strobe **Inclosure Material:** Ceramic **Inclosure Configuration:** Leadless flat pack **Output Logic Form:** N-type metal oxide-semiconductor logic **Input Circuit Pattern:** 13 input **Current Rating Per Characteristic:** 50.00 milliamperes forward current, peak total value not applicable **Terminal Surface Treatment:** Solder **Voltage Rating And Type Per Characteristic:** 7.0 volts total supply **Time Rating Per Chacteristic:** 120.00 nanoseconds propagation delay time, low to high level output and 120.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Ram **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 18 leadless Shelf Life: N/a

No

**Unit Of Measure:** 

Demilitarization:

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